

### **DESCRIPTION**

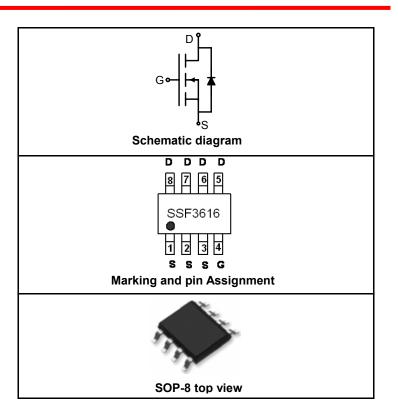
The SSF3616 uses advanced trench technology to provide excellent  $R_{\text{DS(ON)}}$  and low gate charge .This device is suitable for use as a load switch or in PWM applications.

# **GENERAL FEATURES**

- $V_{DS} = 30V, I_D = 9A$   $R_{DS(ON)} < 30m\Omega @ V_{GS} = 4.5V$  $R_{DS(ON)} < 18.5m\Omega @ V_{GS} = 10V$
- High Power and current handing capability
- Lead free product is acquired
- Surface Mount Package

# **Application**

- ●PWM applications
- Load switch
- Power management



### PACKAGE MARKING AND ORDERING INFORMATION

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
SSF3616	SSF3616	SOP-8	Ø330mm	12mm	3000 units

ABSOLUTE MAXIMUM RATINGS(TA=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	30	V
Gate-Source Voltage	V <sub>GS</sub>	±25	V
Desir Comment Continuous & Comment Dulged (Nate 1)	I <sub>D</sub>	9	Α
Drain Current-Continuous@ Current-Pulsed (Note 1)	I <sub>DM</sub>	40	Α
Maximum Power Dissipation	P <sub>D</sub>	2.5	W
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 150	°C

### THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ heta JA}$	62.5	°C/W
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## ELECTRICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	30			V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =30V,V <sub>GS</sub> =0V			1	μΑ



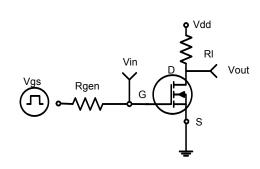
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V			±100	nA
ON CHARACTERISTICS (Note 3)	<u>"</u>				1	I
Gate Threshold Voltage	rreshold Voltage $V_{GS(th)}$ $V_{DS}$ = $V_{GS}$ , $I_D$ =250 $\mu$ A		8.0	1.3	1.8	V
Drain-Source On-State Resistance	$R_{DS(ON)} = V_{GS}=4.5V, I_D=7A$ $V_{GS}=10V, I_D=9A$	V <sub>GS</sub> =4.5V, I <sub>D</sub> =7A		21	30	mΩ
Dialii-Source Oil-State Resistance			16	18.5	mΩ	
Forward Transconductance	<b>g</b> FS	$V_{DS}$ =15 $V$ , $I_{D}$ =9 $A$		10		S
DYNAMIC CHARACTERISTICS (Note4)						
Input Capacitance	C <sub>lss</sub>			600		PF
Output Capacitance	Coss	$V_{DS}$ =15V, $V_{GS}$ =0V, F=1.0MHz		75		PF
Reverse Transfer Capacitance	C <sub>rss</sub>			45		PF
SWITCHING CHARACTERISTICS (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>			4		nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DS}$ =15V, $V_{GS}$ =10V, $R_{GEN}$ =6 $\Omega$		12		nS
Turn-Off Delay Time	t <sub>d(off)</sub>	I <sub>D</sub> =1A		22		nS
Turn-Off Fall Time	t <sub>f</sub>			4		nS
Total Gate Charge	Qg			12		nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =15V,I <sub>D</sub> =9A,V <sub>GS</sub> =10V		1.2		nC
Gate-Drain Charge	$Q_{gd}$			3.8		nC
Body Diode Reverse Recovery Time	T <sub>rr</sub>	1 =0A d1/d+=400A/v.c		13		nS
Body Diode Reverse Recovery Charge	Q <sub>rr</sub>	- I <sub>F</sub> =9A, dl/dt=100A/μs		7		nC
DRAIN-SOURCE DIODE CHARACTERISTIC	S	•			•	•
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =3A		0.7	1.2	V
	•	•			•	•

# **NOTES:**

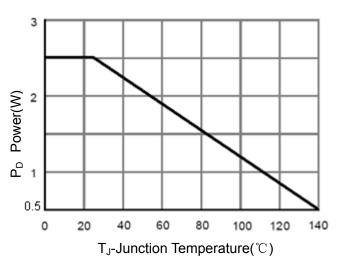
- Repetitive Rating: Pulse width limited by maximum junction temperature.
   Surface Mounted on 1in² FR4 Board, t ≤ 10 sec.
   Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
   Guaranteed by design, not subject to production testing.



## TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS



**Figure 1:Switching Test Circuit** 



**Figure 3 Power Dissipation** 

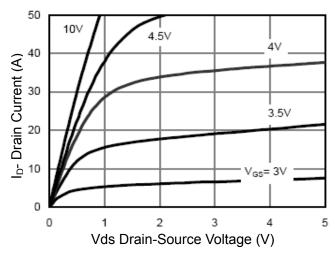
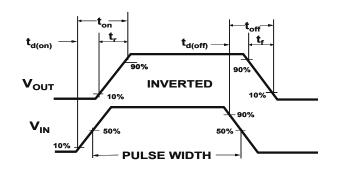
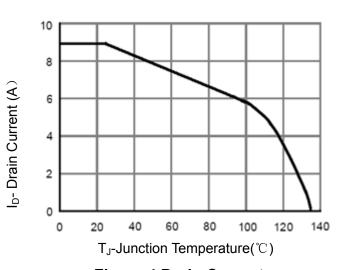


Figure 5 Output CHARACTERISTICS



**Figure 2:Switching Waveforms** 



**Figure 4 Drain Current** 

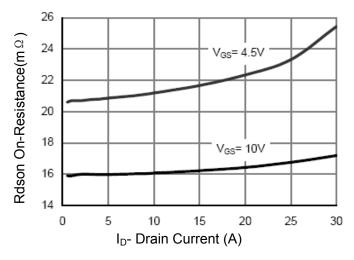
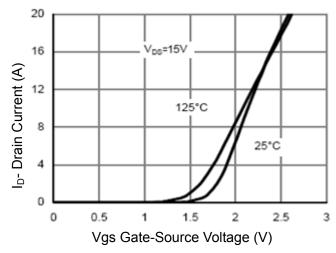


Figure 6 Drain-Source On-Resistance





**Figure 7 Transfer Characteristics** 

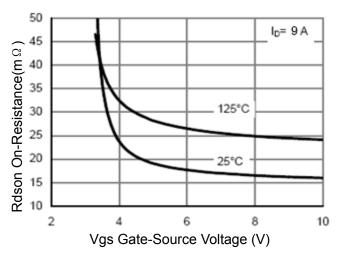


Figure 9 Rdson vs Vgs

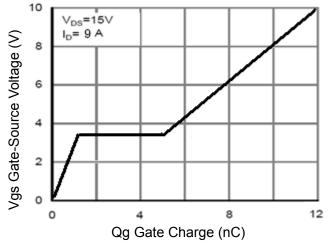


Figure 11 Gate Charge

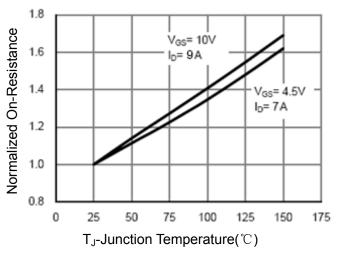


Figure 8 Drain-Source On-Resistance

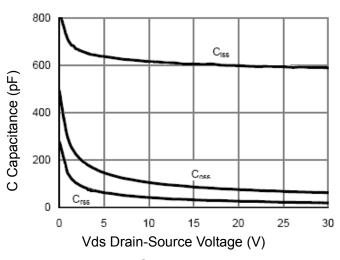


Figure 10 Capacitance vs Vds

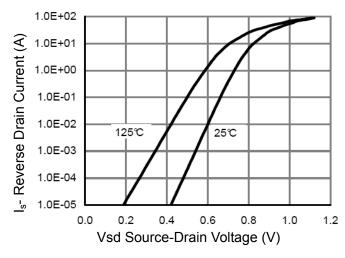


Figure 12 Source- Drain Diode Forward



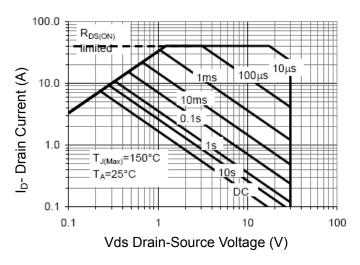
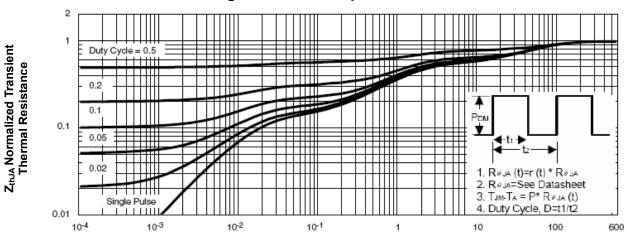


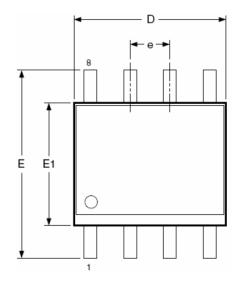
Figure 13 Safe Operation Area

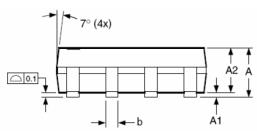


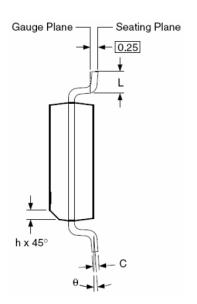
Square Wave Pluse Duration(sec)
Figure 14 Normalized Maximum Transient Thermal Impedance



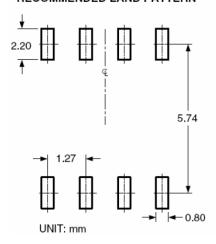
# **SOP-8 PACKAGE INFORMATION**







## RECOMMENDED LAND PATTERN



Dimensions in millimeters						
Symbols	Min.	Nom.	Max.			
Α	1.35	1.65	1.75			
A1	0.10	_	0.25			
A2	1.25	1.50	1.65			
b	0.31	_	0.51			
С	0.17	_	0.25			
D	4.80	4.90	5.00			
E1	3.80	3.90	4.00			
е	1.27 BSC					
E	5.80	6.00	6.20			
h	0.25	_	0.50			
L	0.40	_	1.27			
θ	0°	_	8°			

Dimensions in inches						
Symbols	Min.	Nom.	Max.			
Α	0.053	0.065	0.069			
A1	0.004	_	0.010			
A2	0.049	0.059	0.065			
b	0.012	_	0.020			
С	0.007	_	0.010			
D	0.189	0.193	0.197			
E1	0.150	0.154	0.157			
Ф	0.050 BSC					
Е	0.228	0.236	0.244			
h	0.010	_	0.020			
L	0.016	_	0.050			
θ	<b>0</b> °	_	8°			

## NOTES:

- Dimensions are inclusive of plating
   Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 6 mils.
- 3. Dimension L is measured in gauge plane.
- 4. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.



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